

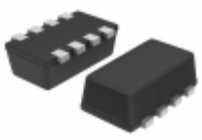
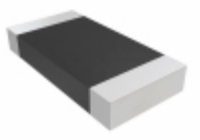
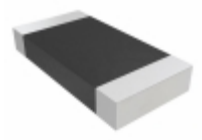
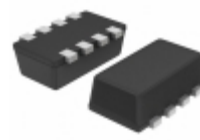

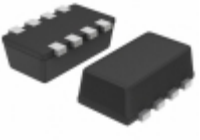


	<h2 style="color: red;">NTHS2101PT1G</h2>
	<p>Hersteller-Teilenummer: NTHS2101PT1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 8V 5.4A CHIPFET</p> <p>Datenblätter:  NTHS2101PT1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 18267 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTHS2101PT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 8V 5.4A CHIPFET
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	18267 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SMD, Flat Lead
Supplier Device-Gehäuse	ChipFET™
Verlustleistung (max)	1.3W (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	8V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	5.4A (Tj)
Rds On (Max) @ Id, Vgs	25 mOhm @ 5.4A, 4.5V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	30nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	2400pF @ 6.4V
Verpackung	Tape & Reel (TR)


















































NTHS2101PT1G ist neu im Original, Suche NTHS2101PT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTHS2101PT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTHS2101PT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTHS2101PT1 AMI Semiconductor / ON Semiconductor MOSFET P-CH 8V 5.4A CHIPFET</p>	 <p>NTHS1206N17N2203JP Dale / Vishay NTC THERMISTOR 220K OHM 5% 1206</p>	 <p>NTHS1206N17N2203JR Dale / Vishay NTC THERMISTOR 220K OHM 5% 1206</p>	 <p>NTHS4101PT1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 4.8A CHIPFET</p>
 <p>NTHS4101PT1 ON NTHS4101PT1 ON</p>	 <p>NTHS4111PT1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 30V 3.3A CHIPFET</p>	 <p>NTHS1210N04N1003JF Dale / Vishay NTC THERMISTOR 100K OHM 5% 1210</p>	 <p>NTHS4111PT1 ON NTHS4111PT1 ON</p>

heiße Teile

Mehr

 NTHD3101FT1	 NTHD3101FT1G	 NTHD3102CT1G	 NTHD310FT1G	 NTHD3133PFT1G
 NTHD4102PT1	 NTHD4102PT1G	 NTHD4401PT1G	 NTHD4401PT3G	 NTHD4502NT1
 NTHD4502NT1G	 NTHD4508NT1	 NTHD4508NT1G	 NTHD4N02FT1	 NTHD4N02FT1G
 NTHD4P02FT1	 NTHD4P02FT1-D	 NTHD4P02FT1G	 NTHD5902	 NTHD5902T1
 NTHD5903T1	 NTHD5903T1G	 NTHD5904N	 NTHD5904NT1	 NTHD5904NT1G
 NTHD5905T1	 NTHD5905T1G	 NTHS0402N02N1002HE	 NTHS0603N01N1003JE	 NTHS0603N02N6801
 NTHS0603N02N6801JE	 NTHS0805N01N5002JE	 NTHS1206N01N4702JE	 NTHS1206N02N1002JR	 NTHS1206N02N1002KR
 NTHS2101PT1	 NTHS4101PT1	 NTHS4101PT1G	 NTHS4111PT1	 NTHS4166NT1G
 NTHS4501NT1	 NTHS4501NT1G	 NTHS5404T1	 NTHS5404T1G	 NTHS5441T1
 NTHS5441T1G	 NTHS5443T1	 NTHS5443T1G	 NTHS5443T1H	 NTHS5445T1

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